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Paper-based WS₂ photodetectors fabricated by all-dry techniques

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A recent application of a simple, all-dry, abrasive transfer of 2D materials on paper demonstrates the potential of two-dimensional tungsten disulfide (WS₂) as the sensitive material of a flexible photoconductive detector. The devices show really good responsivity over a bandwidth spanning from near infrared to ultraviolet and could open new avenues towards disposable optoelectronics systems.

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In the last decades, several applications based on the pervasiveness of inexpensive, versatile, environmentally friendly electronic devices have been envisioned, ranging from mobile healthcare to entertainment, to wearable systems (body trackers, smart textiles, etc.), to countless others. These applications will be based on the convergence of several new technologies, such as flexible substrates and new versatile high-performance materials. Among the former, paper is an extremely appealing choice, because of its biodegradability and negligible cost, allowing the development of systems, which can have a reduced environmental impact at the end of their life cycle^{1,2}. From the technological point of view, the main challenges concerned with device fabrication on paper are related to the high surface roughness, the limited thermal budget (around 120 °C) and the poor stability (especially with respect to humidity), which requires purposely tailored fabrication techniques. 2D materials can represent an enabling technology for paper-based electronics and optoelectronics systems, due to their outstanding properties for apparently any class of applications, and naturally suited for flexible applications³⁻⁷. However, integration of 2D materials on paper sub-

strates presents important challenges that have not been yet satisfactorily addressed. The most common transfer techniques of 2D materials on flexible substrates, such as liquid-assisted layer transfer or printing, requires exposure of the paper to various solvents and/or drying steps, both of which quickly degrade the substrate: for this reason, dry transfer techniques are of great interest^{8,9}.

Within this context, researchers led by Castellanos-Gomez and Xie proposed an all-dry, inexpensive fabrication method based on abrasion of WS₂ (tungsten disulfide) on paper to fabricate photoconductive detectors covering a bandwidth from near infrared to ultraviolet¹⁰. Their maximum responsivity (a measure of the conversion efficiency of the input light to the output current) is significantly higher than those of similar devices in the literature. The main drawback is that the devices are negatively impacted by exposure to ambient oxygen, suggesting the need of an encapsulating layer to improve their performance.

The fabrication process is remarkable in its use of readily available materials and simple and effective techniques, which has been previously developed by Castellanos-Gomez's group^{11,12}. Specifically, a cotton swab is

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used to transfer WS₂ powder on a standard printer paper substrate, essentially exfoliating single flakes from the van der Waals material into a relatively thick (around 20 μm) layer (Fig. 1(a)). The rough paper surface ensures a larger effective area (and a consequent higher responsivity). The device geometry (around 2 mm) is defined by protecting the paper with removable adhesive tape. The electrical contacts are similarly created with a soft graphite pencil, simultaneously defining the active channel length (of around 250 μm at least). Alternatively, a narrower channel (45 μm) is obtained by evaporating thin (100 nm) gold contacts through a shadow mask. Both fabrication paths avoid liquid solvents and high temperature processing.

The fabricated devices exhibit a reversible and repeatable resistance modulation under bending of the paper substrate, a fact that can be attributed to flake-on-flake sliding and consequent change of the overlap area. The devices are also sensitive to oxygen: their dark current (i.e., the current under no illumination) reversibly increase around fivefold if the device is moved from ambient air to oxygen-deprived air or to vacuum.

The primary figure of merit of photoconductive detectors is the responsivity \mathcal{R} (measured in A/W⁻¹), defined as the ratio between the device photocurrent I_{ph} and the corresponding incident light power P :

$$I_{ph} = \mathcal{R} \cdot P.$$

To ensure consistency in the characterization, responsivity measurements were performed in vacuum. In this condition, the WS₂ devices shown very good linearity (i.e., a responsivity essentially independent from the input power). In general, the responsivity is expected to be an increasing function of the bias voltage, and the devices under test showed a dramatic increase moving

from 5 to 35 V, up to a responsivity of around 0.27 A/W in graphene/WS₂ devices at 617 nm (red-orange) light. Predictably, Au/WS₂ devices, owing to their shorter length, presented a much higher responsivity than the equivalent graphene/WS₂ ones.

A comparison with other photodetectors in the literature shows superior responsivity performance, both with respect to devices on flexible substrates based on other photoconductive materials (such as WSe₂), and also to other WS₂ devices based on more traditional, solvent-free deposition methods such as sputtering or chemical vapor deposition (CVD).

Systematic characterization of several identical devices showed a moderate dispersion of the responsivities, which is not unexpected because of the inherently percolative nature of conduction paths through the randomly arranged WS₂ flakes, and which clearly represents a limiting aspect with respect to other deposition techniques as CVD, which, as a point of strength, allows better material uniformity.

Another important figure of merit, which has been widely investigated and compared against the results available in the literature is the response time, able to provide relevant information regarding the speed of the photodetector. The measured values are of the order of seconds, in line with other photodetectors fabricated through solution processed techniques (e.g., inkjet printing, drop casting, dip coating, etc.), but way larger (several order of magnitude) as compared to CVD or sputtering: this is clearly the current limitation of the proposed technique, which can hamper its exploitation in high-speed optoelectronic systems. It is anyway undoubtful that the adopted technique is probably the best (and cheapest) for a really fast prototyping of

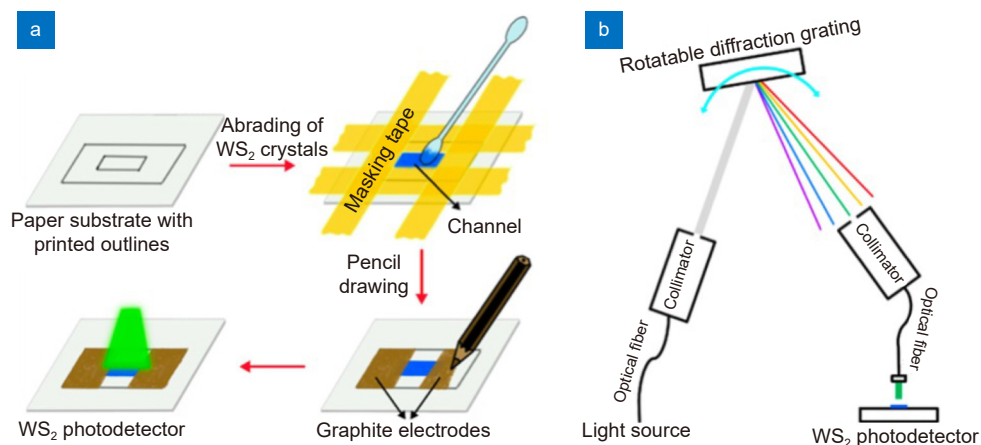


Fig. 1 | (a) Sketch of the fabrication process. (b) Schematic of the set-up for the testing of the proof-of-concept spectrometer.¹⁰

optoelectronic devices, and, while it cannot be used in all those applications where fast response of the photodetectors is required (smaller than 10^{-3} s), it can be exploited whenever the bandwidth of the signal is limited. This is, for example, the case for biosignals, where the proposed technology could enable a wide range of disposable electronic applications¹³.

As a demonstration of the potential of the fabrication technology, authors have exploited the detectors in a proof-of-concept spectrometer (Fig. 1(b)), showing remarkable correspondence with the spectra determined with a commercial silicon photodiode, which demonstrates the possibility of fabricating cost-effective and high-performance electronic/optoelectronic devices on biofriendly substrates as the paper.

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Author contributions

All authors contributed to the manuscript.